#### **DESCRIPTION**

The US1AF~US1MF are available in SMAF package

# ORDERING INFORMATION

Package Type	Part Number				
	US1AF				
SMAF	US1BF				
	US1DF				
	US1GF US1JF				
					US1KF
	US1MF				
	Note	SPQ: 3,000pcs/Reel			
AiT provides all RoHS Compliant Products					

# PIN DESCRIPTION



# **FEATURES**

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Easy to pick and place
- High efficiency
- Fast reverse recovery time
- Available in SMAF package

#### **MECHANICAL DATA**

Case: SMAF

Terminals: Solderable per MIL-STD-750,

Method 2026

Approx. Weight: 27mg 0.00086oz

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# MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter		Symbol	US1AF	US1BF	US1DF	US1GF	US1JF	US1KF	US1MF	Unit
Maximum Repetitive Peak		$V_{RRM}$	50	100	200	400	600	800	1000	٧
Reverse Voltage										
Maximum RMS Volta	ge	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blockir	ig Voltage	V <sub>DC</sub>	50	100	200	400	600	600	100	V
Maximum Average Forward Rectified Current at T <sub>A</sub> =65°C		I <sub>F(AV)</sub>	1.0						Α	
Peak Forward Surge Current 8.3ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)		I <sub>FSM</sub>	25					Α		
Maximum Instantaneous Forward Voltage at 1A		VF		1.0 1.4 1.7					٧	
Maximum DC Reverse Current at Rated DC Blocking Voltage	T <sub>A</sub> =25°C T <sub>A</sub> =125°C	I <sub>R</sub>	5.0 100				μΑ			
Maximum Reverse Recovery TimeNOTE1		t <sub>rr</sub>	50 75				ns			
Typical Thermal Resistance		R <sub>0JA</sub>	180						°C/W	
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>		-55 ~150						°C

NOTE1: Measured with I<sub>F</sub>=0.5A, I<sub>R</sub>=1A, I<sub>rr</sub>=0.25A

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#### TYPICAL CHARACTERISTICS

Figure. 1 Forward Current Derating Curve

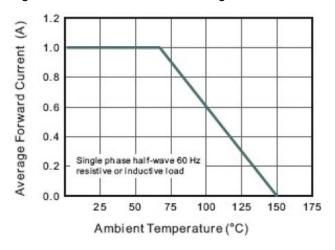


Figure. 3 Typical Instantaneous Forward Characteristics

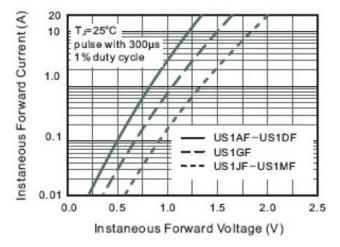


Figure. 2 Typical Reverse Characteristics

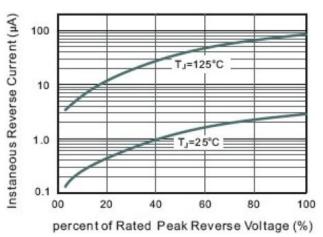
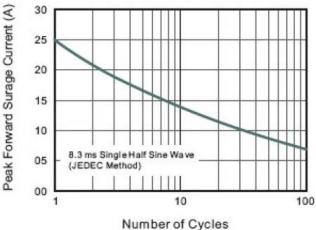


Figure. 4 Maximum Non-Repetitive Peak Forward Surge Current

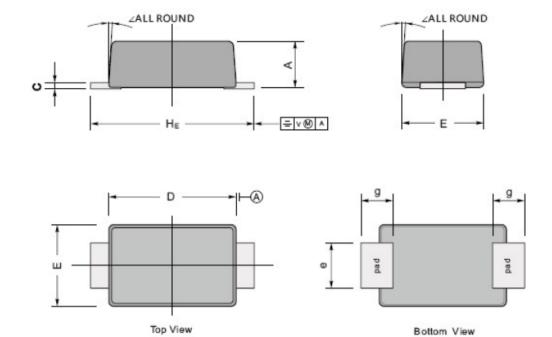


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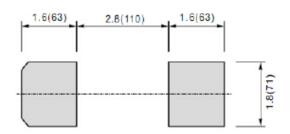
# **PACKAGE INFORMATION**

Dimension in SMAF (Unit: mm)

Plastic surface mounted package; 2 leads



#### The recommended mounting pad size



Unit: mm(mil)

UN	NIT	Α	C	D	E	е	g	HE		
mm	Max	1.3	0.23	3.7	2.7	1.6	1.3	4.9		
	Min	1.1	0.18	3.3	2.4	1.3	1.0	4.4	<b>7</b> °	
mil	Max	51	9.1	146	106	63	51	193	/	
	Min	43	7.1	130	94	51	39	173		

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